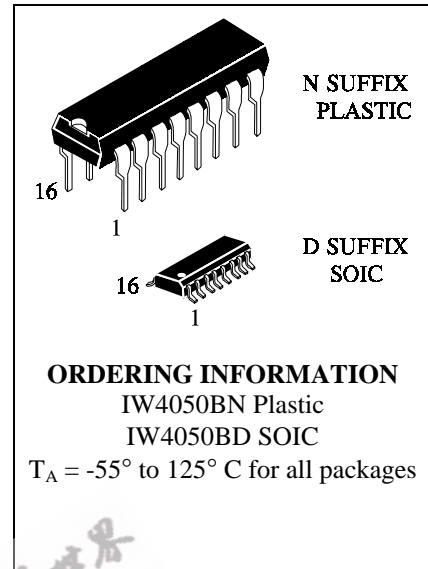


**IW4050B**

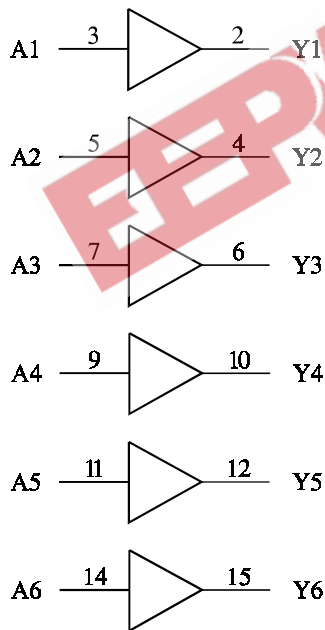
**Hex Buffer/Converter**  
**High-Voltage Silicon-Gate CMOS**

The IW4050B is noninverting hex buffers and feature logic-level conversion using only one supply (voltage  $V_{CC}$ ). The input-signal high level ( $V_{IH}$ ) can exceed the  $V_{CC}$  supply voltage when these devices are used for logic-level conversions. These devices are intended for use as CMOS to DTL/TTL converters.

- Operating Voltage Range: 3.0 to 18 V
- Maximum input current of 1  $\mu$ A at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package temperature range):  
 1.0 V min @ 5.0 V supply  
 2.0 V min @ 10.0 V supply  
 2.5 V min @ 15.0 V supply
- High-to-low level conversion



**LOGIC DIAGRAM**



PINS 13, 16 = NO CONNECTION  
 PIN 1 =  $V_{CC}$   
 PIN 8 = GND

**PIN ASSIGNMENT**

$V_{CC}$	1 ●	16	NC
Y1	2	15	Y6
A1	3	14	A6
Y2	4	13	NC
A2	5	12	Y5
Y3	6	11	A5
A3	7	10	Y4
GND	8	9	A4

NC = NO CONNECTION

**FUNCTION TABLE**

Inputs	Output
A	Y
L	L
H	H

**MAXIMUM RATINGS\***

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	-0.5 to +20	V
V <sub>IN</sub>	DC Input Voltage (Referenced to GND)	V <sub>CC</sub> ** to +18	V
V <sub>OUT</sub>	DC Output Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IN</sub>	DC Input Current, per Pin	±10	mA
P <sub>D</sub>	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
P <sub>D</sub>	Power Dissipation per Output Transistor	100	mW
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

\*Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C

SOIC Package: : - 7 mW/°C from 65° to 125°C

\*\* The IW4050B has high-to-low level voltage conversion capability but not low-to-high level; therefore it is recommended that V<sub>IN</sub> ≥ V<sub>CC</sub>

**RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	3.0	18	V
V <sub>IN</sub>	DC Input Voltage (Referenced to GND)	V <sub>CC</sub> **	18	V
V <sub>OUT</sub>	DC Output Voltage (Referenced to GND)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature, All Package Types	-55	+125	°C

\*\* The IW4050B has high-to-low level voltage conversion capability but not low-to-high level; therefore it is recommended that V<sub>IN</sub> ≥ V<sub>CC</sub>

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V<sub>IN</sub> and V<sub>OUT</sub> should be constrained to the range GND ≤ (V<sub>IN</sub> or V<sub>OUT</sub>) ≤ V<sub>CC</sub>.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

## DC ELECTRICAL CHARACTERISTICS(Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	Guaranteed Limit			Unit
				≥-55°C	25°C	≤125°C	
V <sub>IH</sub>	Minimum High-Level Input Voltage	V <sub>OUT</sub> = V <sub>CC</sub> - 0.5V V <sub>OUT</sub> = V <sub>CC</sub> - 1.0 V V <sub>OUT</sub> = V <sub>CC</sub> - 1.5V	5.0	3.5	3.5	3.5	V
			10	7	7	7	
			15	11	11	11	
V <sub>IL</sub>	Maximum Low-Level Input Voltage	V <sub>OUT</sub> = 0.5V V <sub>OUT</sub> = 1.0 V V <sub>OUT</sub> = 1.5V	5.0	1.5	1.5	1.5	V
			10	3	3	3	
			15	4	4	4	
V <sub>OH</sub>	Minimum High-Level Output Voltage	V <sub>IN</sub> = V <sub>CC</sub>	5.0	4.95	4.95	4.95	V
			10	9.95	9.95	9.95	
			15	14.95	14.95	14.95	
V <sub>OL</sub>	Maximum Low-Level Output Voltage	V <sub>IN</sub> =GND	5.0	0.05	0.05	0.05	V
			10	0.05	0.05	0.05	
			15	0.05	0.05	0.05	
I <sub>IN</sub>	Maximum Input Leakage Current	V <sub>IN</sub> = GND or V <sub>CC</sub>	18	±0.1	±0.1	±1.0	μA
I <sub>CC</sub>	Maximum Quiescent Supply Current (per Package)	V <sub>IN</sub> = GND or V <sub>CC</sub>	5.0	1	1	30	μA
			10	2	2	60	
			15	4	4	120	
			20	20	20	600	
I <sub>OL</sub>	Minimum Output Low (Sink) Current	V <sub>IN</sub> = GND or V <sub>CC</sub> U <sub>OL</sub> =0.4 V U <sub>OL</sub> =0.4 V U <sub>OL</sub> =0.5 V U <sub>OL</sub> =1.5 V	4.5	3.3	2.6	1.8	mA
			5	4	3.2	2.4	
			10	10	8	5.6	
			15	26	24	18	
I <sub>OH</sub>	Minimum Output High (Source) Current	V <sub>IN</sub> = GND or V <sub>CC</sub> U <sub>OH</sub> =2.5 V U <sub>OH</sub> =4.6 V U <sub>OH</sub> =9.5 V U <sub>OH</sub> =13.5 V	5.0	-2.6	-2.1	-1.55	mA
			5.0	-0.81	-0.65	-0.48	
			10	-2.0	-1.65	-1.18	
			15	-5.2	-4.3	-3.1	

**AC ELECTRICAL CHARACTERISTICS**( $C_L=50\text{pF}$ ,  $R_L=200\text{k}\Omega$ , Input  $t_r=t_f=20\text{ ns}$ )

Symbol	Parameter	$V_{IN}$ V	$V_{CC}$ V	Guaranteed Limit			Unit
				$\geq -55^\circ\text{C}$	$25^\circ\text{C}$	$\leq 125^\circ\text{C}$	
$t_{PLH}$	Maximum Propagation Delay, Input A to Output Y (Figure 1)	5	5	140	140	280	ns
		10	10	80	80	160	
		10	5	90	90	180	
		15	15	60	60	120	
		15	5	80	80	160	
$t_{PHL}$	Maximum Propagation Delay, Input A to Output Y (Figure 1)	5	5	110	110	220	ns
		10	10	55	55	110	
		10	5	100	100	200	
		15	15	30	30	60	
		15	5	100	100	200	
$t_{TLH}$	Maximum Output Transition Time, Any Output (Figure 1)	5	5	160	160	320	ns
		10	10	80	80	160	
		15	15	60	60	120	
$t_{THL}$	Maximum Output Transition Time, Any Output (Figure 1)	5	5	60	60	120	ns
		10	10	40	40	80	
		15	15	30	30	60	
$C_{IN}$	Maximum Input Capacitance	-	-	-	7.5	-	pF

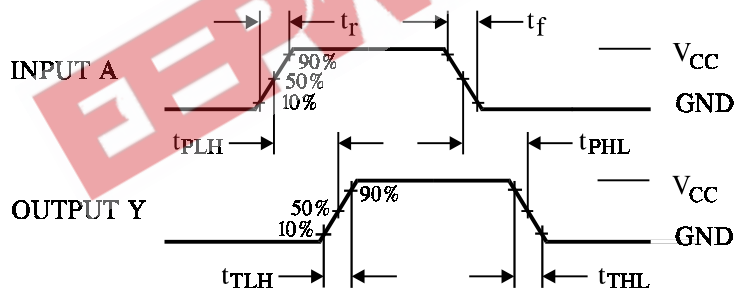


Figure 1. Switching Waveforms

**EXPANDED LOGIC DIAGRAM**  
(1/6 of the Device)

